

## <mark>捷多邦,专业PCB打样工厂,24小时加急出货</mark>



# DDC (LO-R1) H

NPN PRE-BIASED SMALL SIGNAL SOT-563 **DUAL SURFACE MOUNT TRANSISTOR** 

#### **Features**

- Epitaxial Planar Die Construction •
- Complementary PNP Types Available • (DDA)
- **Built-In Biasing Resistors** .
- Lead Free By Design/RoHS Compliant (Note 3) •

#### **Mechanical Data**

- Case: SOT-563, Molded Plastic •
- Case Material: Molded Plastic. UL Flammability • Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C •
- Terminals: Finish - Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.005 grams (approx.) •

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDC122LH DDC142JH DDC122TH DDC122TH DDC142TH	0.22KΩ 0.47KΩ 0.22KΩ 0.47KΩ	10KΩ 10KΩ OPEN OPEN	N81 N82 N83 N84

M ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓

Pb Lead-free

SOT-563									
Dim	Min	Мах	Тур						
Α	0.15	0.30	0.25						
В	1.10	1.25	1.20						
С	1.55 1.70 1.60								
D	0.50								
G	0.90	1.10	1.00						
Н	1.50	1.50 1.70 1.60							
к	0.56	0.60 0.60							
L	0.15	.15 0.25 0.20							
М	0.10	0.18	0.11						
All	Dimens	ions in	mm						

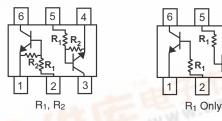
5

2

4

3

SEE NOTE 1



SCHEMATIC DIAGRAM, TOP VIEW

#### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	n750.00	Symbol	Value	Unit V	
Supply Voltage (6) to (1) and (3) to (4)	1.00	V <sub>CC</sub>	50		
Input Voltage (2) to (1) and (5) to (4)	DDC122LH DDC142JH	V <sub>IN</sub>	-5 to +6 -5 to +6	V	
Input Voltage (1) to (2) and (4) to (5)	DDC122TH DDC142TH	V <sub>EBO</sub> (MAX)	5	TOLON	
Output Current	All	lc	100	mA mA	
Power Dissipation		Pd	150	mW	
Thermal Resistance, Junction to Ambient	Air (Note 2)	R <sub>0JA</sub>	833	°C/W	

1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

2. Mounted on FR4 Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.

3. No purposefully added lead.



Note:



. ..

Electrical Characteristic	unless otherwise specified					R1, R2 Types		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
Input Voltage	DDC122LH DDC142JH	V <sub>l(off)</sub>	0.3 0.3			V	$V_{CC}=5V,\ I_{O}=100\mu A$	
	DDC122LH DDC142JH	V <sub>l(on)</sub>		_			$V_{O} = 0.3V, I_{O} = 20mA$ $V_{O} = 0.3V, I_{O} = 20mA$	
Output Voltage		V <sub>O(on)</sub>		_	0.3V	V	$I_{O}/I_{I} = 5mA/0.25mA$	
Input Current DDC122LH DDC142JH		lı		_	28 13	mA	$V_I = 5V$	
Output Current		I <sub>O(off)</sub>		—	0.5	μA	$V_{CC}=50V,V_I=0V$	
DC Current Gain DDC122LH DDC142JH		Gı	56 56	_	_	_	$V_{O} = 5V, I_{O} = 10mA$	
Gain-Bandwidth Product*		f⊤		200		MHz	$V_{CE} = 10V$ , $I_E = 5mA$ , f = 100MHz	

**R1-Only** 

\* Transistor - For Reference Only

#### **Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic Max Unit **Test Condition** Symbol Min Тур Collector-Base Breakdown Voltage  $\mathsf{BV}_{\mathsf{CBO}}$ 50 V  $I_C = 50 \mu A$ \_  $I_C = 1mA$ Collector-Emitter Breakdown Voltage **BV**CEO 40 V \_\_\_\_ \_\_\_\_ Emitter-Base Breakdown Voltage DDC122TH  $I_E = 50 \mu A$  $\mathsf{BV}_{\mathsf{EBO}}$ 5 \_\_\_\_ V DDC142TH  $I_{E} = 50 \mu A$ Collector Cutoff Current  $V_{CB} = 50V$  $I_{\text{CBO}}$ 0.5 μA \_\_\_\_ DDC122TH DDC142TH 0.5 0.5 \_ **Emitter Cutoff Current**  $V_{\text{EB}} = 4V$  $I_{\text{EBO}}$ μΑ Collector-Emitter Saturation Voltage  $I_{C} = 5mA, I_{B} = 0.25mA$ V<sub>CE(sat)</sub> 0.3 V \_\_\_\_ \_\_\_\_ DDC122TH DDC142TH 600 100 250 DC Current Transfer Ratio  $I_C = 1mA$ ,  $V_{CE} = 5V$ h<sub>FE</sub> 250 100 600  $V_{CE} = 10V, I_E = -5mA, f = 100MHz$ Gain-Bandwidth Product\*  $\mathbf{f}_{\mathsf{T}}$ 200 MHz

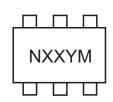
\* Transistor - For Reference Only

#### Ordering Information (Note 4)

Device	Packaging	Shipping
DDC122LH-7	SOT-563	3000/Tape & Reel
DDC142JH-7	SOT-563	3000/Tape & Reel
DDC122TH-7	SOT-563	3000/Tape & Reel
DDC142TH-7	SOT-563	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

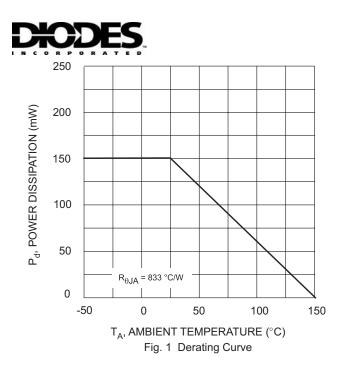
### **Marking Information**



 $\begin{array}{l} \mathsf{NXX} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \ (\mathsf{See} \ \mathsf{Page} \ \mathsf{1}) \\ \mathsf{YM} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \mathsf{Y} = \mathsf{Year} \ \mathsf{ex:} \ \mathsf{T} = \mathsf{2006} \\ \mathsf{M} = \mathsf{Month} \ \mathsf{ex:} \ \mathsf{9} = \mathsf{September} \end{array}$ 

Date Code Key

Year	2002	2003	2004	2005	2006	200	7 20	08 2	009	2010	2011	2012
Code	N	Р	R	S	Т	U	\	/	W	Х	Y	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	Jan	100	3	Арі	5	6		8	· ·		N	Dec
									9			



#### IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

#### LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.